捷多邦,专业PCB**·SN54AH@T@40**章**SN7**4AHCT240 OCTAL BUFFERS/DRIVERS WITH 3-STATE OUTPUTS

SCLS252I - OCTOBER 1995 - REVISED JANUARY 2000

- EPIC™ (Enhanced-Performance Implanted CMOS) Process
- Inputs Are TTL-Voltage Compatible
- Latch-Up Performance Exceeds 250 mA Per JESD 17
- Package Options Include Plastic Small-Outline (DW), Shrink Small-Outline (DB), Thin Very Small-Outline (DGV), Thin Shrink Small-Outline (PW), and Ceramic Flat (W) Packages, Ceramic Chip Carriers (FK), and Standard Plastic (N) and Ceramic (J) DIPs

description

These octal buffers/drivers are designed specifically to improve the performance and density of 3-state memory-address drivers, clock drivers, and bus-oriented receivers and transmitters.

The 'AHCT240 devices are organized as two 4-bit buffers/line drivers with separate output-enable (\overline{OE}) inputs. When \overline{OE} is low, the device passes data from the A inputs to the Y outputs. When \overline{OE} is high, the outputs are in the high-impedance state.

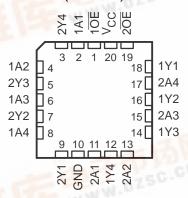
To ensure the high-impedance state during power up or power down, \overline{OE} should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

The SN54AHCT240 is characterized for operation over the full military temperature range of -55°C to 125°C. The SN74AHCT240 is characterized for operation from -40°C to 85°C.

SN54AHCT240 . . . J OR W PACKAGE SN74AHCT240 . . . DB, DGV, DW, N, OR PW PACKAGE (TOP VIEW)

	_		
10E [1	20] V _{CC}
1A1 [2	19	2OE
2Y4 [3	18] 1Y1
1A2 [4		
2Y3 [16	
1A3 [6	15	7 2A3
2Y2 [7	14	1Y3
1A4 [8	13] 2A2
2Y1 [9	12] 1Y4
GND [10	11	2A1

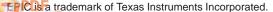
SN54AHCT240 . . . FK PACKAGE (TOP VIEW)



FUNCTION TABLE (each 4-bit buffer/driver)

(oddir i bit barrorranivor)							
INPUTS		OUTPUT					
OE	Α	Υ					
L	Н	(() L					
L	L	Н					
Н	Χ	Z					

Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

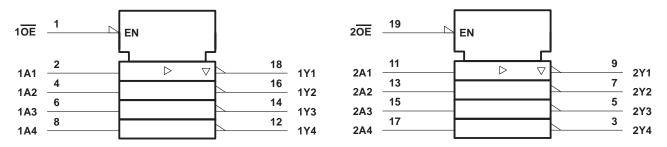




SN54AHCT240, SN74AHCT240 OCTAL BUFFERS/DRIVERS WITH 3-STATE OUTPUTS

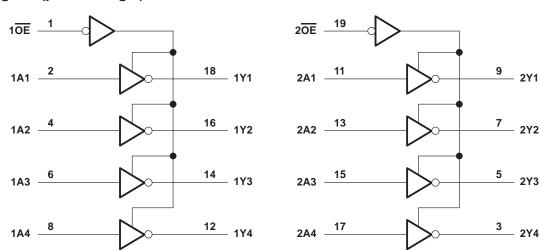
SCLS252I - OCTOBER 1995 - REVISED JANUARY 2000

logic symbol†



[†]This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

logic diagram (positive logic)



absolute maximum ratings over operating free-air temperature range (unless otherwise noted)‡

Supply voltage range, V_{CC}	DB package DGV package DW package N package	-0.5 V to 7 V -0.5 V to V _{CC} + 0.5 V -20 mA -20 mA -25 mA -25 mA -70°C/W -92°C/W -58°C/W -69°C/W
Storage temperature range, T _{stq}	PW package	83°C/W
Storage temperature range, 1stg		03 0 10 130 0

[‡] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.



NOTES: 1. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

^{2.} The package thermal impedance is calculated in accordance with JESD 51.

SCLS252I - OCTOBER 1995 - REVISED JANUARY 2000

recommended operating conditions (see Note 3)

		SN54AH	CT240	SN74AH	UNIT	
		MIN	MAX	MIN	MAX	UNIT
Vcc	Supply voltage	4.5	5.5	4.5	5.5	V
VIH	High-level input voltage	2		2		V
V _{IL}	Low-level input voltage		0.8		0.8	V
٧ı	Input voltage	0	5.5	0	5.5	V
Vo	Output voltage	0	VCC	0	VCC	V
IOH	High-level output current		-8		-8	mA
loL	Low-level output current		8		8	mA
TA	Operating free-air temperature	- 55	125	-40	85	°C

NOTE 3: All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	Vaa	T _A = 25°C			SN54AHCT240		SN74AHCT240		UNIT
PARAMETER	TEST CONDITIONS	Vcc	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNIT
Maria	I _{OH} = -50 μA	4.5 V	4.4	4.5		4.4		4.4		V
VOH	I _{OH} = -8 mA	4.5 V	3.94			3.8		3.8		
VOL	I _{OL} = 50 μA	4.5 V			0.1		0.1		0.1	V
	I _{OL} = 8 mA	4.5 V			0.36		0.44		0.44	V
loz	$V_O = V_{CC}$ or GND	5.5 V			±0.25		±2.5		±2.5	μΑ
lį	V _I = V _{CC} or GND	0 V to 5.5 V			±0.1		±1*		±1	μΑ
Icc	$V_I = V_{CC}$ or GND, $I_O = 0$	5.5 V			4		40		40	μΑ
ΔI _{CC} †	One input at 3.4 V, Other inputs at V _{CC} or GND	5.5 V			1.35		1.5		1.5	mA
Ci	V _I = V _{CC} or GND	5 V		2.5	10				10	pF
Co	V _O = V _{CC} or GND	5 V		3						pF

^{*} On products compliant to MIL-PRF-38535, this parameter is not production tested at $V_{CC} = 0 \text{ V}$.



[†] This is the increase in supply current for each input at one of the specified TTL voltage levels rather than 0 V or VCC.

SN54AHCT240, SN74AHCT240 OCTAL BUFFERS/DRIVERS WITH 3-STATE OUTPUTS

SCLS252I - OCTOBER 1995 - REVISED JANUARY 2000

switching characteristics over recommended operating free-air temperature range, V_{CC} = 5 V \pm 0.5 V (unless otherwise noted) (see Figure 1)

PARAMETER	FROM	то	LOAD	TΔ	= 25°C	;	SN54AH	CT240	SN74AH	CT240	UNIT
PARAMETER	(INPUT)	(OUTPUT)	CAPACITANCE	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNIT
t _{PLH}	Α	Y	C _L = 15 pF		5.4*	7.4*	1*	8.5*	1	8.5	ns
t _{PHL}	A	'	CL = 13 pr		5.4*	7.4*	1*	8.5*	1	8.5	115
^t PZH	OE	Y	C _L = 15 pF		7.7*	10.4*	1*	12*	1	12	
t _{PZL}	OE	Ť	CL = 13 pr		7.7*	10.4*	1*	12*	1	12	ns
^t PHZ	ŌĒ	Y	C _I = 15 pF		8.3*	10.4*	1*	12*	1	12	ns
t _{PLZ}	OL	•	, OL = 13 bi		8.3*	10.4*	1*	12*	1	12	113
t _{PLH}	А	Y	C. 50 pF		5.9	8.4	1	9.5	1	9.5	
tPHL	A	Ť	C _L = 50 pF		5.9	8.4	1	9.5	1	9.5	ns
t _{PZH}	ŌĒ	Y	C ₁ = 50 pF		8.2	11.4	1	13	1	13	ns
t _{PZL}	OE	'	CL = 30 pr		8.2	11.4	1	13	1	13	115
t _{PHZ}	ŌĒ	Y	C: - 50 pE		8.8	11.4	1	13	1	13	ne
tPLZ		ſ	C _L = 50 pF		8.8	11.4	1	13	1	13	ns
^t sk(o)			C _L = 50 pF			1**				1	ns

^{*} On products compliant to MIL-PRF-38535, this parameter is not production tested.

noise characteristics, $V_{CC} = 5 \text{ V}$, $C_L = 50 \text{ pF}$, $T_A = 25^{\circ}\text{C}$ (see Note 4)

PARAMETER				SN74AHCT240		
				MAX	UNIT	
V _{OH(V)}	Quiet output, minimum dynamic V _{OH}		4.1		V	
V _{IH(D)}	High-level dynamic input voltage	2			V	
V _{IL(D)}	Low-level dynamic input voltage			0.8	V	

NOTE 4: Characteristics are for surface-mount packages only.

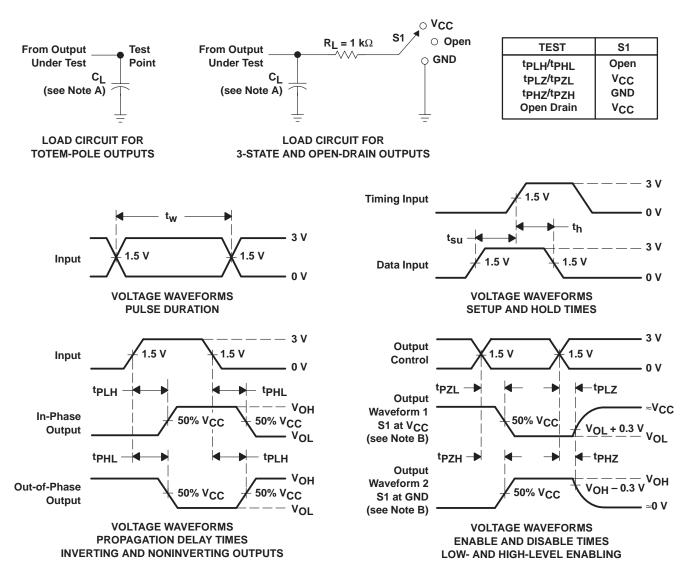
operating characteristics, $V_{CC} = 5 \text{ V}$, $T_A = 25^{\circ}\text{C}$

PARAMETER		TEST C	ONDITIONS	TYP	UNIT
C _{pd}	Power dissipation capacitance	No load,	f = 1 MHz	10	pF

^{**} On products compliant to MIL-PRF-38535, this parameter does not apply.

SCLS252I - OCTOBER 1995 - REVISED JANUARY 2000

PARAMETER MEASUREMENT INFORMATION



NOTES: A. C_L includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 1 MHz, $Z_Q = 50 \Omega$, $t_f \leq$ 3 ns, $t_f \leq$ 3 ns.
- D. The outputs are measured one at a time with one input transition per measurement.

Figure 1. Load Circuit and Voltage Waveforms



IMPORTANT NOTICE

Texas Instruments and its subsidiaries (TI) reserve the right to make changes to their products or to discontinue any product or service without notice, and advise customers to obtain the latest version of relevant information to verify, before placing orders, that information being relied on is current and complete. All products are sold subject to the terms and conditions of sale supplied at the time of order acknowledgement, including those pertaining to warranty, patent infringement, and limitation of liability.

TI warrants performance of its semiconductor products to the specifications applicable at the time of sale in accordance with TI's standard warranty. Testing and other quality control techniques are utilized to the extent TI deems necessary to support this warranty. Specific testing of all parameters of each device is not necessarily performed, except those mandated by government requirements.

CERTAIN APPLICATIONS USING SEMICONDUCTOR PRODUCTS MAY INVOLVE POTENTIAL RISKS OF DEATH, PERSONAL INJURY, OR SEVERE PROPERTY OR ENVIRONMENTAL DAMAGE ("CRITICAL APPLICATIONS"). TI SEMICONDUCTOR PRODUCTS ARE NOT DESIGNED, AUTHORIZED, OR WARRANTED TO BE SUITABLE FOR USE IN LIFE-SUPPORT DEVICES OR SYSTEMS OR OTHER CRITICAL APPLICATIONS. INCLUSION OF TI PRODUCTS IN SUCH APPLICATIONS IS UNDERSTOOD TO BE FULLY AT THE CUSTOMER'S RISK.

In order to minimize risks associated with the customer's applications, adequate design and operating safeguards must be provided by the customer to minimize inherent or procedural hazards.

TI assumes no liability for applications assistance or customer product design. TI does not warrant or represent that any license, either express or implied, is granted under any patent right, copyright, mask work right, or other intellectual property right of TI covering or relating to any combination, machine, or process in which such semiconductor products or services might be or are used. TI's publication of information regarding any third party's products or services does not constitute TI's approval, warranty or endorsement thereof.

Copyright © 2000, Texas Instruments Incorporated